

Form PTO-1449 U.S. Department of Commerce (Rev. 8-83) Patent and Trademark Office		Attorney Docket No. 0756-1653		Serial No. 08/818,884		
INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)		Applicant: Shunpei YAMAZAKI, et al.				
		Filing Date: September 5, 2000		Group: 2871		
FOREIGN PATENT DOCUMENTS						
	Document Number	Date	Country	Class	Subclass	Translation Yes No
DN	0 161 555*	11/1983	EP	-	-	
	0 321 073*	06/1989	EP	-	-	
	0 337 457	10/18/89	EP	-	-	
	49-77537*	07/1974	JP	-	-	X
	55-011329*	01/1980	JP	-	-	Full
	55-32026*	03/1980	JP	-	-	Full
	55-029154*	03/1980	JP	-	-	Full
	55-050664*	04/1980	JP	-	-	Full
	55-050663*	04/1980	JP	-	-	Full
	55-82458*	06/1980	JP	-	-	Abstract
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DN	59-072182*	04/1984	JP	-	-	Full
Examiner: DNQUEN		Date Considered: 9/18/04				
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(Rev. 8-83) Patent and Trademark Office

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Applicant: Shunpei YAMAZAKI, et al.

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Document Number	Date	Country	Class	Subclass	Translation Yes No
DN 59-072128*	04/1984	JP	-	-	Full
59-115574*	07/1984	JP	-	-	Full
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Examiner DN4UHEN Date Considered 9/18/04

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Submitted with IDS of October 24, 2000

Form PTO-1449 U.S. Department of Commerce (Rev. 8-83) Patent and Trademark Office INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)				Attorney Docket No. 0756-2230		Serial No. 08/818,884	
				Applicant: Shunpei YAMAZAKI, et al.			
				Filing Date: September 5, 2000		Group: 2871	
FOREIGN PATENT DOCUMENTS							
	Document Number	Date	Country	Class	Subclass	Translation Yes	No
DN	1-130131*	05/1989	JP	-	-	Abstract	
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	2-51129*	02/1990	JP	-	-	Abstract	
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	2-115824*	04/1990	JP	-	-	Abstract	
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Examiner <u>DNULLEN</u>				Date Considered <u>9/18/04</u>			
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	Document Number	Date	Country	Class	Subclass	Translation Yes No	
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Examiner <u>DN444EN</u>				Date Considered <u>09/18/04</u>			
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OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)			
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		Scheid, et al., A Super Large Grain Polycrystalline Silicon Obtained From Pyrolysis of Si ₂ H ₆ and Annealing@, J. Appl. Phys., Vol. 29, No. 11, Nov. 1990, pp. L 2105-2107*	
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Examiner DN WEN		Date Considered 9/18/04	
<small>*EXAMINER: Initial if citation considered, whether or not citation is in substantiation with MPWP 600. Draw line through citation if not in substantiation and not considered. Include copy of this form with next communication to applicant.</small>			

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Substitute for form 1449A/PTO		Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>		Application Number	08/818,884
		Filing Date	March 17, 1997
		First Named Inventor	Shunpei YAMAZAKI et al.
		Group Art Unit	2871
		Examiner Name	D. Nguyen
		Attorney Docket Number	0756-1653
Sheet	1	of	1

U.S. PATENT DOCUMENTS					
Examiner Initials ¹	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY
		Number	Kind Code ² (if known)		
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		Office ²	Number ²	Kind Code ² (if known)			
DN		EP	0 553 775		—	08/04/1993	Eng.
DN		EP	0 554 063		—	08/04/1993	Eng.
DN		JP	05-249495		—	09/28/1993	Abst.
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DN		JP	06-250214		—	09/09/1994	Abst.

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
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Examiner Signature	DUNG NGUYEN	Date Considered	09/16/04
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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				Complete if Known	
Application Number		08/818,884			
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DN		JP	63-208896			08/30/1988		Full

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